



AF/2815

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: EMA, Taiji

Serial No.: 09/050,113

Filed: March 30, 1998

Corres. and Mail

BOX AF

Group Art Unit: 2815

Examiner: Matthew E. Warren

P.T.O. Confirmation No.: 6454

For: SEMICONDUCTOR DEVICE INCLUDING CONTACT HOLES BETWEEN  
ADJACENT CONDUCTOR PATTERNS AND METHOD FOR FABRICATING THE  
SAME

RESPONSE UNDER 37 CFR §1.116

- EXPEDITED RESPONSE -  
GROUP ART UNIT 2815

Mailstop After Final  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

July 23, 2003

Sir:

In response to the Office Action dated April 23, 2003, please amend the above identified application as follows:

IN THE CLAIMS:

AMEND claims 2 and 36 as follows:

2. (Six Times Amended) A semiconductor device comprising:

a base substrate;

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a first conducting film formed over the base substrate and including a plurality of conductor patterns adjacent to each other;

an etching stopper film covering an upper surface of the conductor patterns;

a contact hole located in a part of a region between the adjacent conductor patterns and having an end thereof defined by the conductor patterns;

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JUL 29 2003